

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|-------|---|---|------------------|---------|------------------|
| L1 | 11146 | (gaas adj3 substrate) and epitax\$4 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/11/16 09:07 |
| L2 | 530 | I1 and (remov\$3 adj substrate) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/11/16 09:08 |
| L3 | 390 | I2 and dop\$3 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/11/16 09:08 |
| S23 | 375 | semiconductor and (defect adj density) and (remov\$3 adj substrate) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/11/15 13:23 |
| S24 | 288 | S23 and epitax\$5 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/11/16 09:06 |